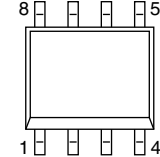
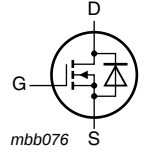


2. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	 SOT96-1 (SO8)	
2	S	source		
3	S	source		
4	G	gate		
5	D	drain		
6	D	drain		
7	D	drain		
8	D	drain		

3. Ordering information

Table 3. Ordering information

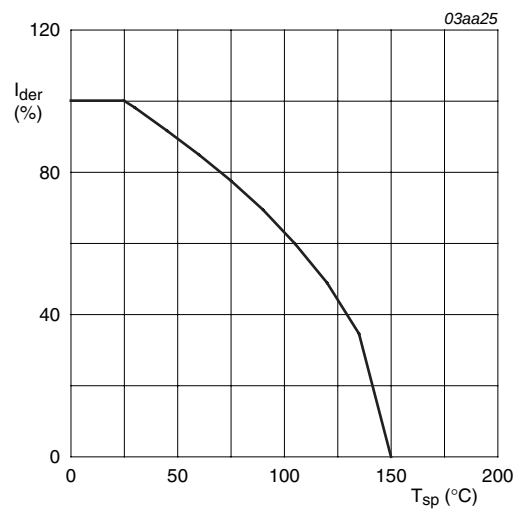
Type number	Package		Version
	Name	Description	
PHK5NQ15T	SO8	plastic small outline package; 8 leads; body width 3.9 mm	SOT96-1

4. Limiting values

Table 4. Limiting values

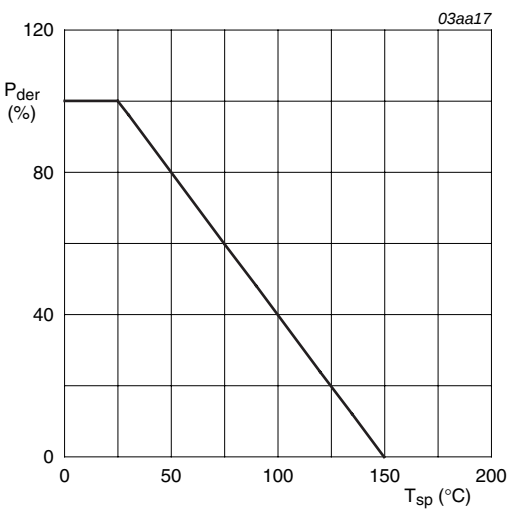
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 150\text{ °C}$	-	150	V
V_{DGR}	drain-gate voltage	$T_j \geq 25\text{ °C}$; $T_j \leq 150\text{ °C}$; $R_{GS} = 20\text{ k}\Omega$	-	150	V
V_{GS}	gate-source voltage		-20	20	V
I_D	drain current	$T_{sp} = 100\text{ °C}$; $V_{GS} = 10\text{ V}$; see Figure 1	-	3.23	A
		$T_{sp} = 25\text{ °C}$; $V_{GS} = 10\text{ V}$; see Figure 1 and 3	-	5	A
I_{DM}	peak drain current	$T_{sp} = 25\text{ °C}$; $t_p \leq 10\text{ }\mu\text{s}$; pulsed; see Figure 3	-	20	A
P_{tot}	total power dissipation	$T_{sp} = 25\text{ °C}$; see Figure 2	-	6.25	W
T_{stg}	storage temperature		-55	150	°C
T_j	junction temperature		-55	150	°C
Source-drain diode					
I_S	source current	$T_{sp} = 25\text{ °C}$	-	5	A
I_{SM}	peak source current	$T_{sp} = 25\text{ °C}$; $t_p \leq 10\text{ }\mu\text{s}$; pulsed	-	20	A



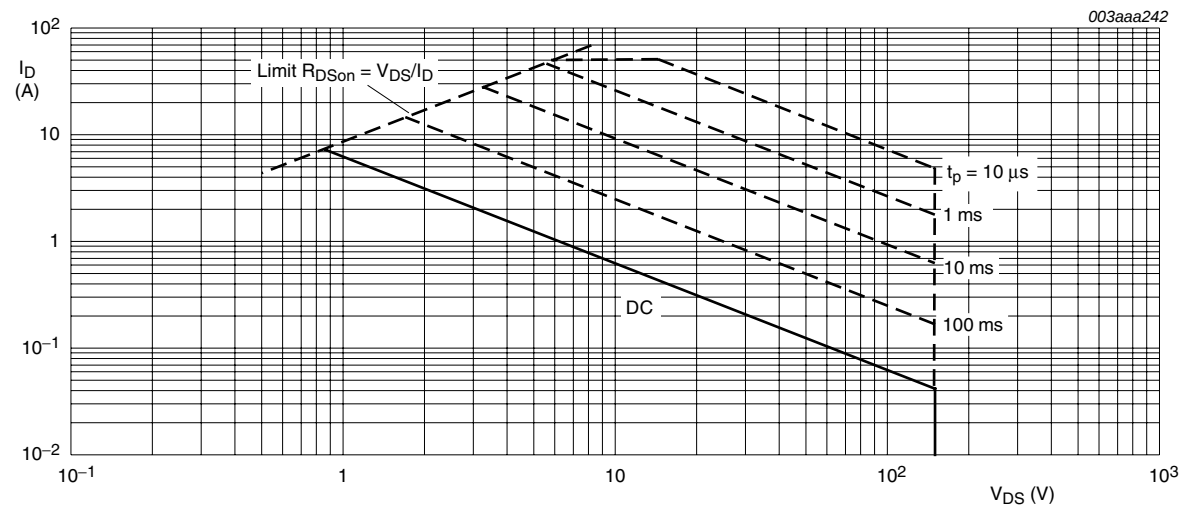
$$I_{der} = \frac{I_D}{I_{D(25^{\circ}\text{C})}} \times 100\%$$

Fig 1. Normalized continuous drain current as a function of solder point temperature



$$P_{der} = \frac{P_{tot}}{P_{tot(25^{\circ}\text{C})}} \times 100\%$$

Fig 2. Normalized total power dissipation as a function of solder point temperature



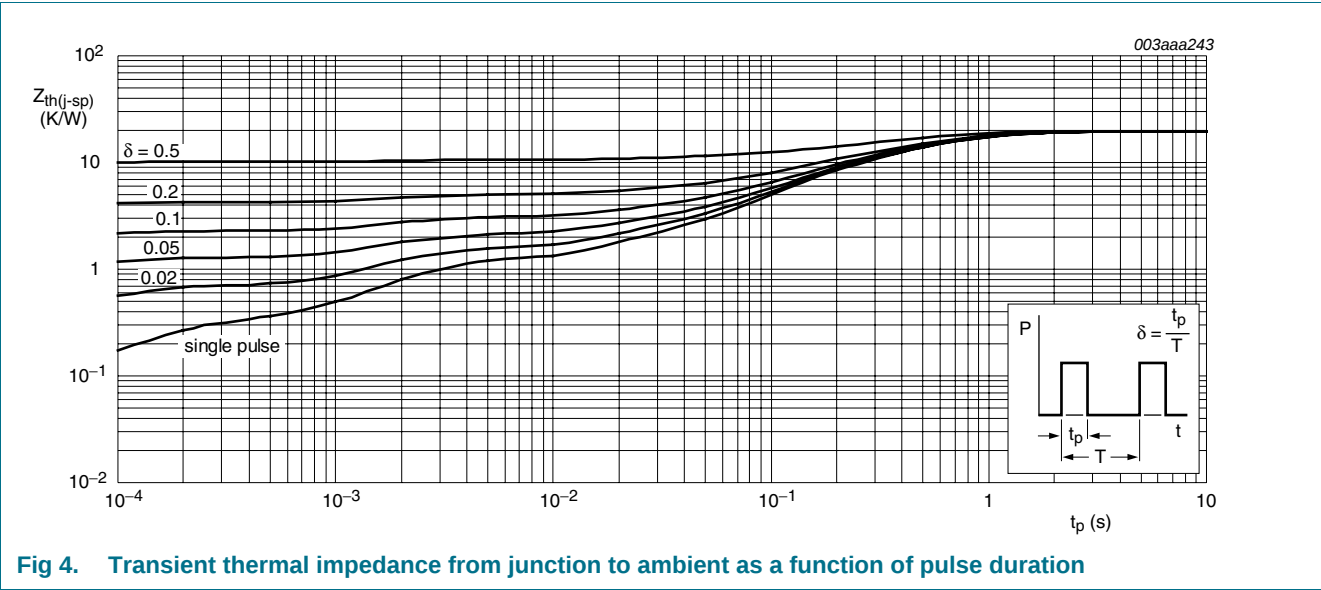
$T_{sp} = 25^{\circ}\text{C}; I_{DM}$ is single pulse;

Fig 3. Safe operating area; continuous and peak drain currents as a function of drain-source voltage

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$R_{th(j-sp)}$	thermal resistance from junction to solder point	see Figure 4	-	-	20	K/W
$R_{th(j-a)}$	thermal resistance from junction to ambient	minimum footprint; mounted on printed-circuit board	-	70	-	K/W



6. Characteristics

Table 6. Characteristics

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static characteristics						
V _{(BR)DSS}	drain-source breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	134	-	-	V
		I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	150	-	-	V
V _{GS(th)}	gate-source threshold voltage	I _D = 1 mA; V _{DS} = V _{GS} ; T _j = -55 °C; see Figure 8	-	-	4.5	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 150 °C; see Figure 8	1.2	-	-	V
		I _D = 1 mA; V _{DS} = V _{GS} ; T _j = 25 °C; see Figure 8	2	3	4	V
I _{DSS}	drain leakage current	V _{DS} = 120 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μA
		V _{DS} = 120 V; V _{GS} = 0 V; T _j = 150 °C	-	-	100	μA
I _{GSS}	gate leakage current	V _{GS} = 10 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
		V _{GS} = -10 V; V _{DS} = 0 V; T _j = 25 °C	-	10	100	nA
R _{DSon}	drain-source on-state resistance	V _{GS} = 10 V; I _D = 5 A; T _j = 150 °C; see Figure 9 and 10	-	129	173	mΩ
		V _{GS} = 5 V; I _D = 3 A; T _j = 25 °C	-	60	80	mΩ
		V _{GS} = 10 V; I _D = 5 A; T _j = 25 °C; see Figure 9 and 10	-	56	75	mΩ
Dynamic characteristics						
Q _{G(tot)}	total gate charge	I _D = 5 A; V _{DS} = 75 V; V _{GS} = 10 V; T _j = 25 °C; see Figure 11	-	29	-	nC
Q _{GS}	gate-source charge		-	3	-	nC
Q _{GD}	gate-drain charge		-	12	-	nC
C _{iss}	input capacitance	V _{DS} = 25 V; V _{GS} = 0 V; f = 1 MHz; T _j = 25 °C; see Figure 12	-	1150	-	pF
C _{oss}	output capacitance		-	187	-	pF
C _{rss}	reverse transfer capacitance		-	61	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 75 V; R _L = 15 Ω; V _{GS} = 10 V; R _{G(ext)} = 6 Ω; T _j = 25 °C; I _D = 5 A	-	12	-	ns
t _r	rise time		-	12	-	ns
t _{d(off)}	turn-off delay time		-	35	-	ns
t _f	fall time		-	18	-	ns
Source-drain diode						
V _{SD}	source-drain voltage	I _S = 5 A; V _{GS} = 0 V; T _j = 25 °C; see Figure 13	-	0.8	1.2	V
t _{rr}	reverse recovery time	I _S = 5 A; dI _S /dt = -100 A/μs; V _{GS} = 0 V;	-	87	-	ns
Q _r	recovered charge	V _{DS} = 90 V; T _j = 25 °C	-	162	-	nC

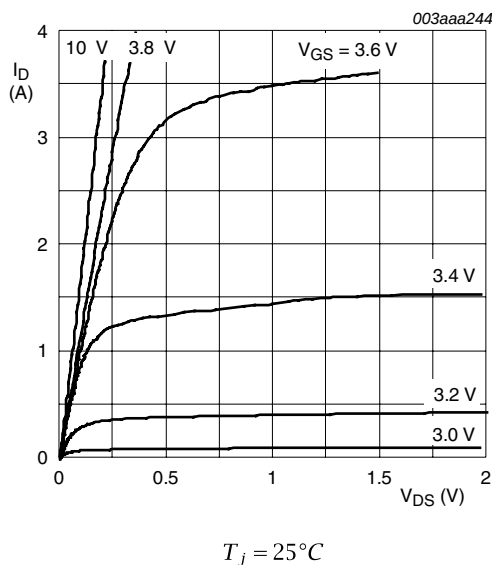


Fig 5. Output characteristics: drain current as a function of drain-source voltage; typical values

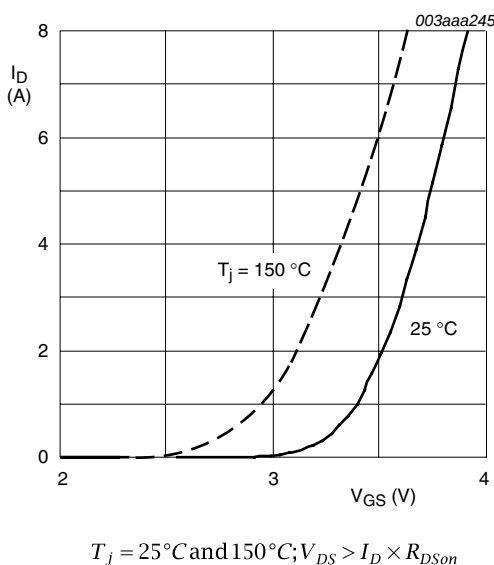


Fig 6. Transfer characteristics: drain current as a function of gate-source voltage; typical values

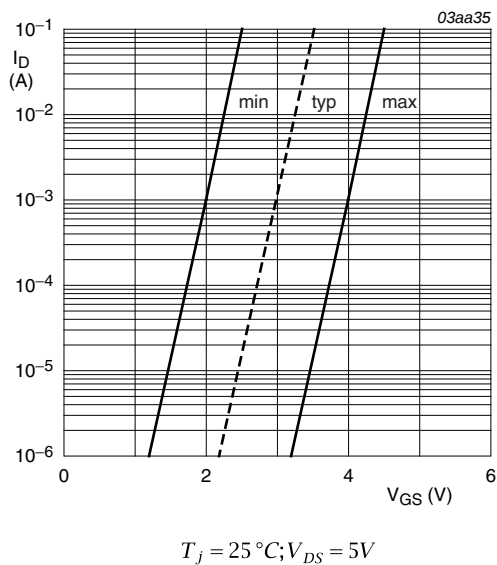


Fig 7. Sub-threshold drain current as a function of gate-source voltage

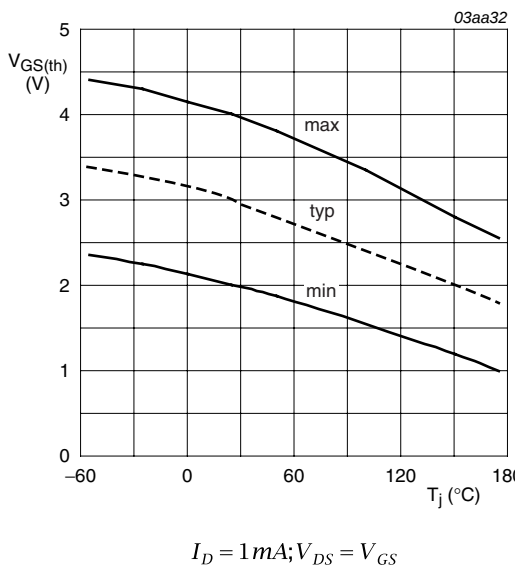


Fig 8. Gate-source threshold voltage as a function of junction temperature

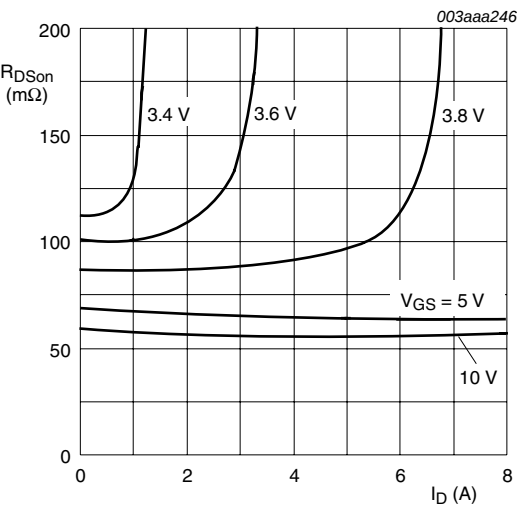
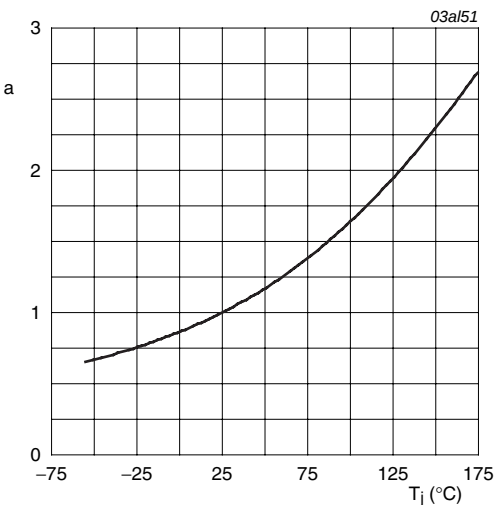
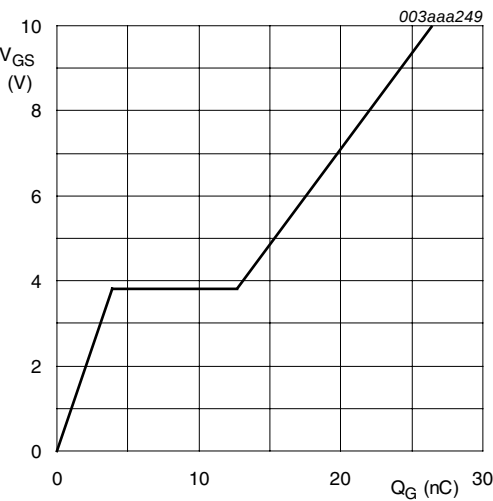


Fig 9. Drain-source on-state resistance as a function of drain current; typical values



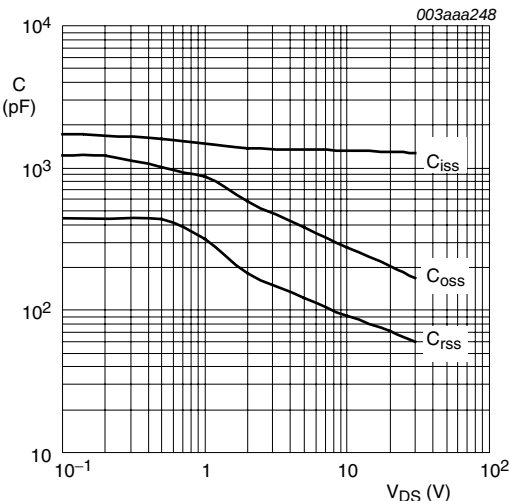
$$a = \frac{R_{DS(on)}}{R_{DS(on)(25^\circ\text{C})}}$$

Fig 10. Normalized drain-source on-state resistance factor as a function of junction temperature



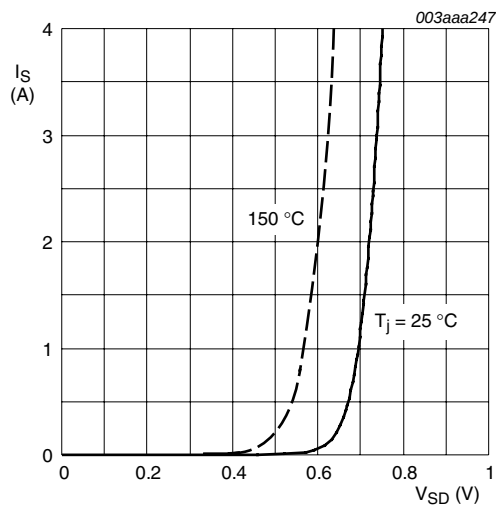
$$I_D = 5\text{ A}; V_{DD} = 75\text{ V}$$

Fig 11. Gate-source voltage as a function of gate charge; typical values



$$V_{GS} = 0\text{ V}; f = 1\text{ MHz}$$

Fig 12. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values



$T_j = 25^\circ\text{C}$ and 150°C ; $V_{GS} = 0\text{V}$

Fig 13. Source current as a function of source-drain voltage; typical values

7. Package outline

SO8: plastic small outline package; 8 leads; body width 3.9 mm

SOT96-1

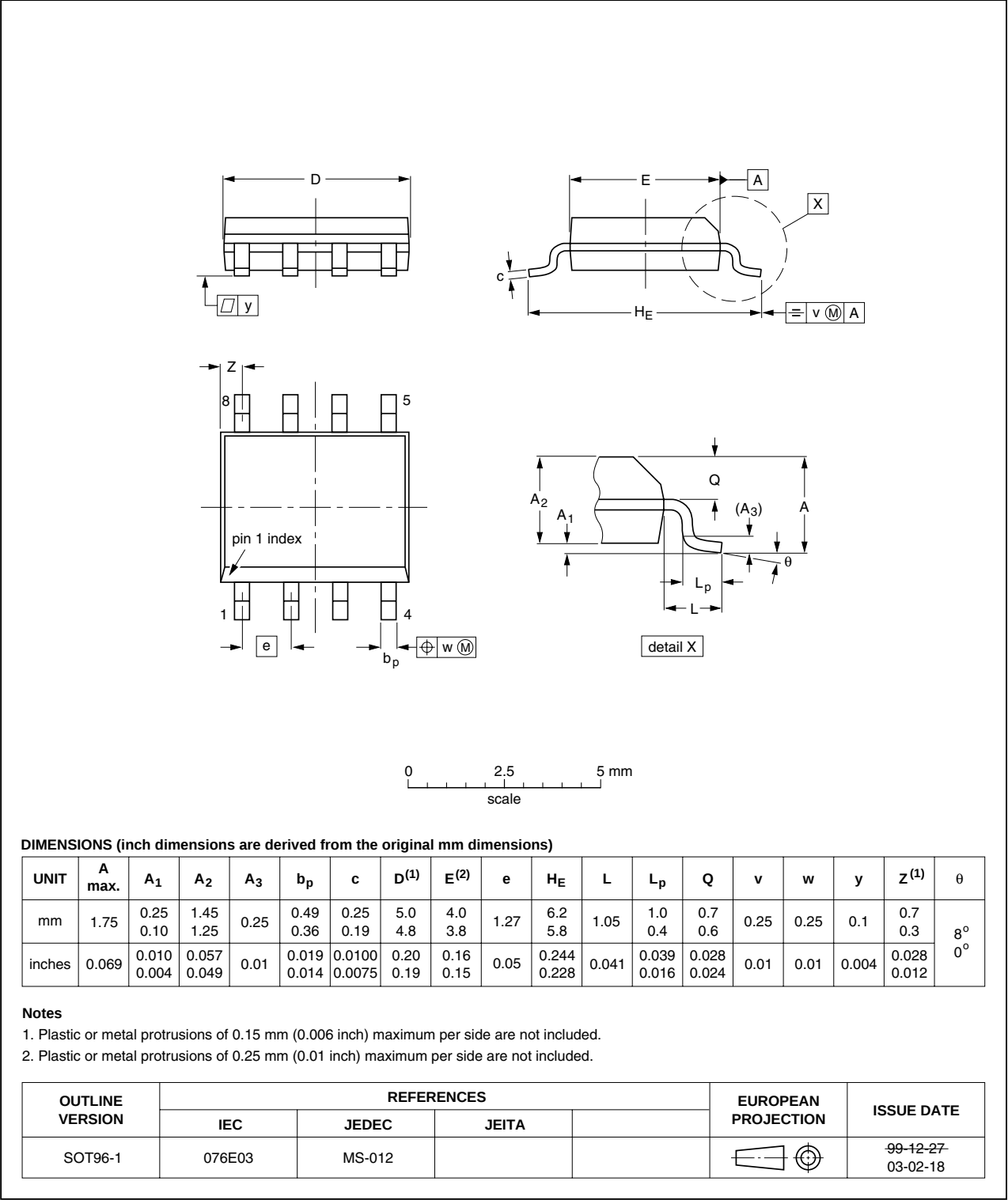


Fig 14. Package outline SOT96-1 (SO8)

8. Revision history

Table 7. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
PHK5NQ15T_2	20100304	Product data sheet	-	PHK5NQ15T-01
Modifications:	- The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. - Legal texts have been adapted to the new company name where appropriate.			
PHK5NQ15T-01	20030120	Product data	-	-

9. Legal information

9.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.nxp.com>.

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